1 Characteristics

Table 1. Absolute maximum ratings (T_j = 25 °C unless otherwise stated)

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	TO-220AB, D²PAK	T_c = 105 °C	12	A
		TO-220AB Ins.	T_c = 90 °C		
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25 °C)	f = 50 Hz	t = 20 ms	120	A
		f = 60 Hz	t_p = 16.7 ms	126	
I^2t	I^2t value for fusing		t_p = 10 ms	78	A^2s
dI/dt	Critical rate of rise of on-state current I_G = 2 x I_{GT}, tr ≤ 100 ns	f = 120 Hz	T_j = 125 °C	50	A/µs
V_{DSM}/V_{RSM}	Non repetitive surge peak off-state voltage	t_p = 10 ms	T_j = 25 °C	V_{DRM} / V_{RRM} + 100	V
I_{GM}	Peak gate current	t_p = 20 µs	T_j = 125 °C	4	A
$P_{G(AV)}$	Average gate power dissipation		T_j = 125 °C	1	W
T_{stg}	Storage junction temperature range			-40 to +150	°C
T_j	Operating junction temperature range			-40 to +125	°C

Table 2. Electrical characteristics (T_j = 25 °C, unless otherwise specified) - Snubberless™ and logic level (3 quadrants)

Symbol	Parameter	Quadrant		T1205 BTB12-TW BTA12-TW	T1210 BTB12-SW BTA12-SW	T1235 BTB12-CW BTA12-CW	T1250 BTB12-BW BTA12-BW	Unit
I_{GT} (1)	V_D = 12 V, R_L = 30 Ω	I - II - III	Max.	5	10	35	50	mA
V_{GT}		I - II - III	Max.	1.3				V
V_{GD}	V_D = V_{DRM}, R_L = 3.3 kΩ, T_j = 125 °C	I - II - III	Min.	0.2				V
I_H (2)	I_T = 100 mA	I - II - III	Max.	10	15	35	50	mA
I_L (2)	I_G = 1.2 x I_{GT}	I - III	Max.	10	25	50	70	mA
		II	Max.	15	30	60	80	
dV/dt (2)	V_D = 67% V_{DRM}, gate open, T_j = 125 °C		Max.	20	40	500	1000	V/µs
(dI/dt)c (2)	(dV/dt)c = 0.1 V/µs, T_j = 125 °C		Min.	3.5	6.5			A/ms
	(dV/dt)c = 10 V/µs, T_j = 125 °C		Min.	1.0	2.9			
	Without snubber, T_j = 125 °C		Min.			6.5	12	

1. *Minimum I_{GT} is guaranteed at 5 % of I_{GT} max.*
2. *For both polarities of A2 referenced to A1*

Table 3. Electrical characteristics (T_j = 25 °C, unless otherwise specified) - Standard Triac (4 quadrants)

Symbol	Parameter	Quadrant		Value		Unit
				C	B	
I_{GT} (1)	V_D = 12 V, R_L = 30 Ω	I - II - III	Max.	25	50	mA
		IV		50	100	
V_{GT}		All	Max.	1.3		V
V_{GD}	V_D = V_{DRM}, R_L = 33 kΩ, T_j = 125 °C	All	Min.	0.2		V
I_H (2)	I_T = 500 mA	I - II - III	Max.	25	50	mA
I_L	I_G = 1.2 I_{GT}	I - III - IV	Max.	40	50	mA
		II		80	100	
dV/dt (2)	V_D = 67 % V_{DRM} gate open, T_j = 125 °C		Min.	200	400	V/µs
(dV/dt)c (2)	(dI/dt)c = 5.3 A/ms, T_j = 125 °C		Min.	5	10	V/µs

1. *Minimum I_{GT} is guaranteed at 5 % of I_{GT} max.*
2. *For both polarities of A2 referenced to A1*

Table 4. Static electrical characteristics

Symbol	Test conditions			Value	Unit
V_{TM} (1)	I_{TM} = 17 A, t_p = 380 µs	T_j = 25 °C	Max.	1.55	V
V_{TO} (1)	threshold on-state voltage	T_j = 125 °C	Max.	0.85	V
R_D (1)	Dynamic resistance	T_j = 125 °C	Max.	35	mΩ
I_{DRM} I_{RRM}	V_{DRM} = V_{RRM}	T_j = 25 °C	Max.	5	µA
		T_j = 125 °C	Max.	1	mA

1. *For both polarities of A2 referenced to A1*

Table 5. Thermal resistance

Symbol	Parameter				Value	Unit
$R_{th(j-c)}$	Max. junction to case thermal resistance (AC)		D^2PAK / TO-220AB	Max.	1.4	°C/W
			TO-220AB insulated	Max.	2.3	
$R_{th(j-a)}$	Junction to ambient	S = 2 cm² (1)	D^2PAK	Typ.	45	°C/W
	Junction to ambient		TO-220AB / TO-220AB insulated	Typ.	60	

1. *S = Copper surface under tab.*

1.1 Characteristics (curves)

Figure 1. Maximum power dissipation versus on-state RMS current (full cycle)

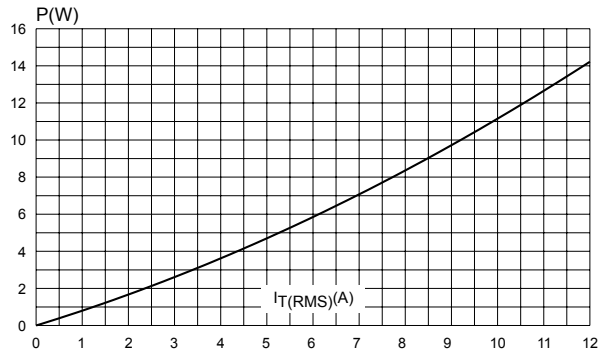


Figure 2. RMS on-state current versus case temperature (full cycle)

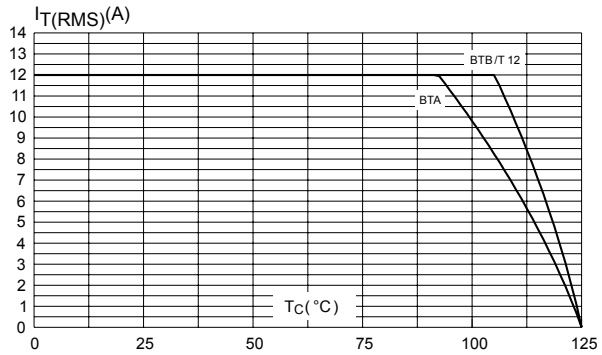


Figure 3. RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness: 35 µm) (full cycle)

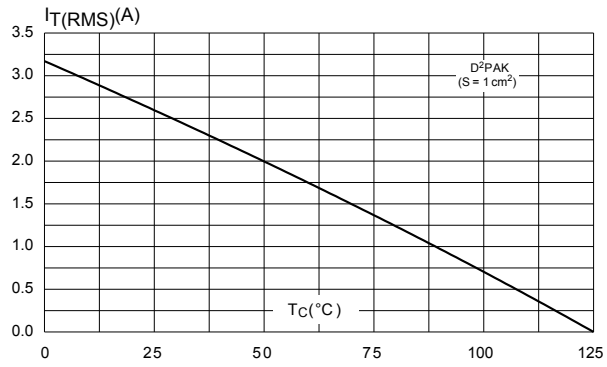


Figure 4. Relative variation of thermal impedance versus pulse duration

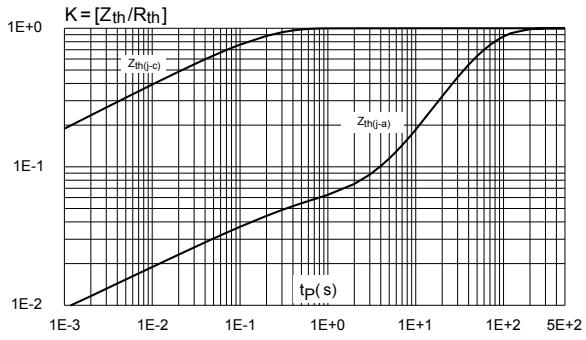


Figure 5. On-state characteristics (maximum values)

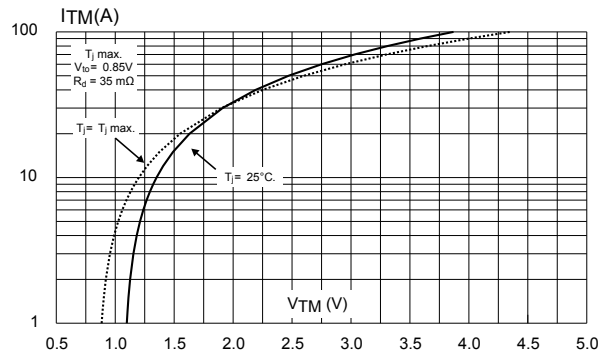


Figure 6. Surge peak on-state current versus number of cycles

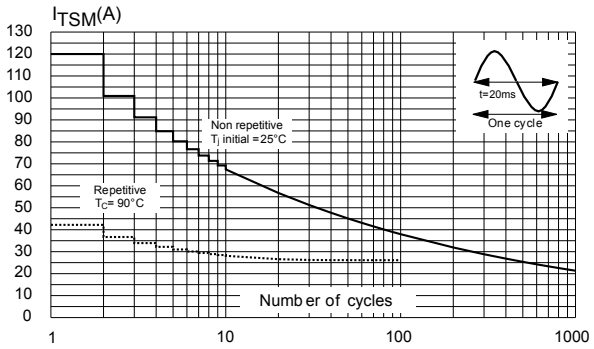


Figure 7. Non repetitive surge peak on-state current for a sinusoidal pulse

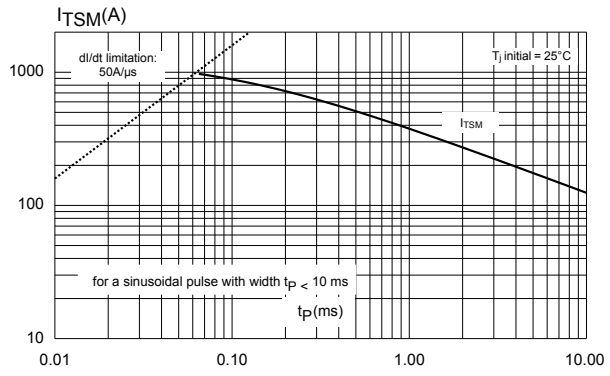


Figure 8. Relative variation of gate trigger current holding current and latching current versus junction temperature (typical values)

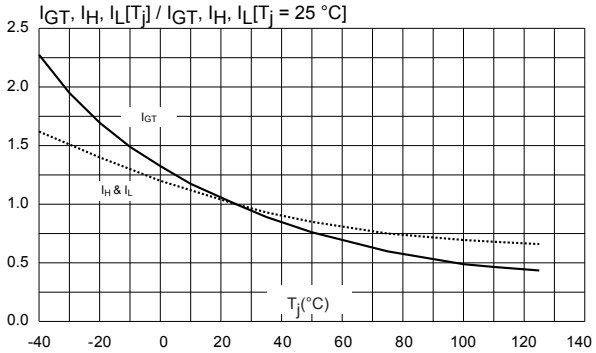


Figure 9. Relative variation of critical rate of decrease of main current versus (dV/dt)c (typical values)

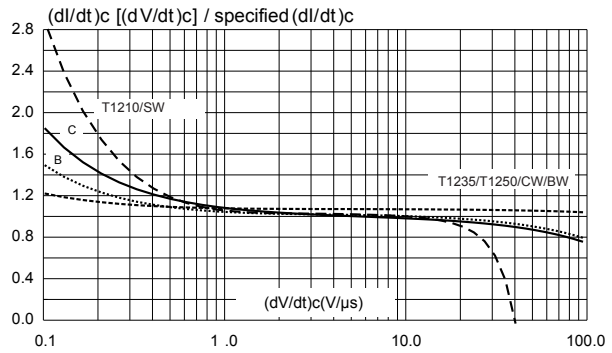


Figure 10. Relative variation of critical rate of decrease of main current versus (dV/dt)c (typical values)(TW)

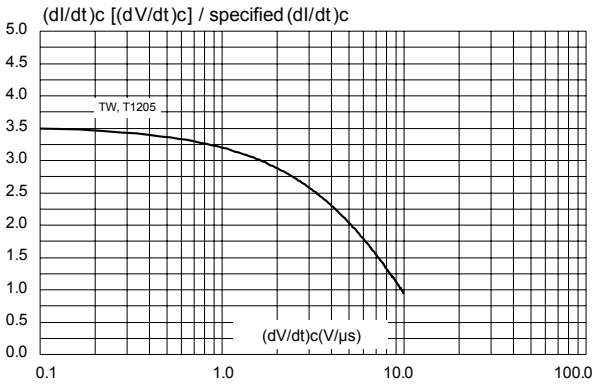


Figure 11. Relative variation of critical rate of decrease of main current versus junction temperature

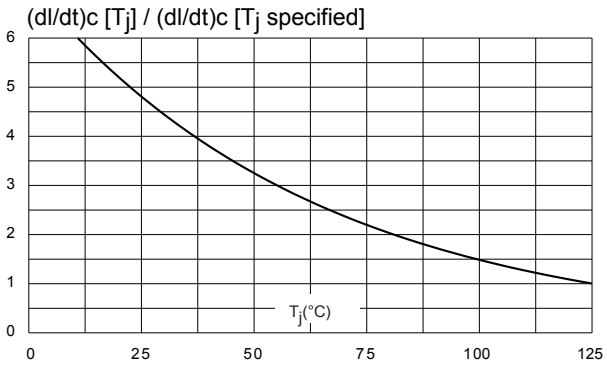
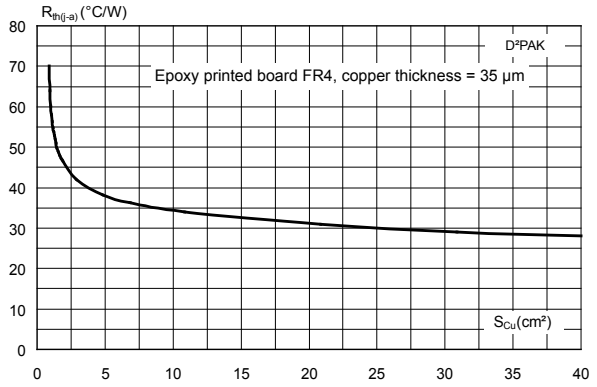


Figure 12. D²PAK thermal resistance junction to ambient versus copper surface under tab



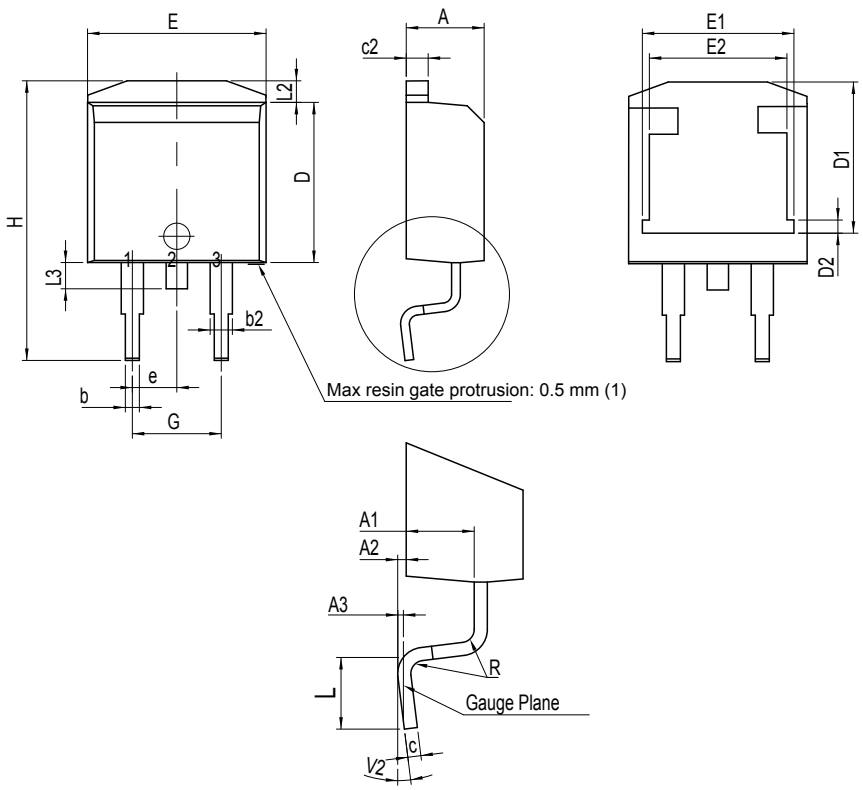
2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

2.1 D²PAK package information

- ECOPACK2® compliant
- Lead-free package leads finishing
- Molding compound resin is halogen-free and meets UL standard level V0

Figure 13. D²PAK package outline



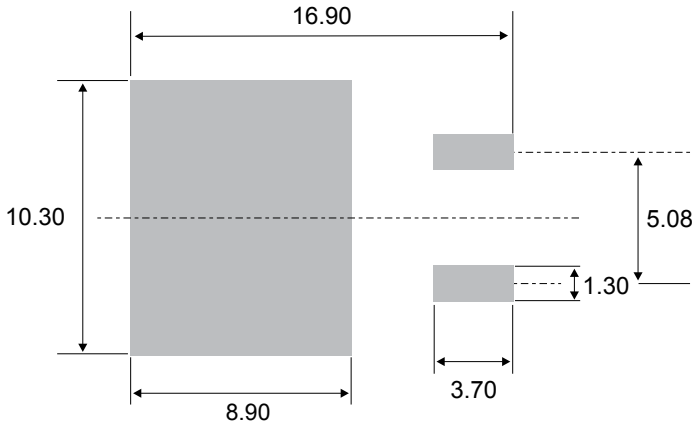
(1) Resin gate is accepted in each of position shown on the drawing, or their symmetrical.

Table 6. **D²PAK package mechanical data**

Ref.	Dimensions					
	Millimeters			Inches[1]		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.30		4.60	0.1693		0.1811
A1	2.49		2.69	0.0980		0.1059
A2	0.03		0.23	0.0012		0.0091
A3		0.25			0.0098	
b	0.70		0.93	0.0276		0.0366
b2	1.25		1.7	0.0492		0.0669
c	0.45		0.60	0.0177		0.0236
c2	1.21		1.36	0.0476		0.0535
D	8.95		9.35	0.3524		0.3681
D1	7.50		8.00	0.2953		0.3150
D2	1.30		1.70	0.0512		0.0669
e	2.54			0.1		
E	10.00		10.28	0.3937		0.4047
E1	8.30		8.70	0.3268		0.3425
E2	6.85		7.25	0.2697		0.2854
G	4.88		5.28	0.1921		0.2079
H	15		15.85	0.5906		0.6240
L	1.78		2.28	0.0701		0.0898
L2	1.27		1.40	0.0500		0.0551
L3	1.40		1.75	0.0551		0.0689
R		0.40			0.0157	
V2	0°		8°	0°		8°

1. *Dimensions in inches are given for reference only*

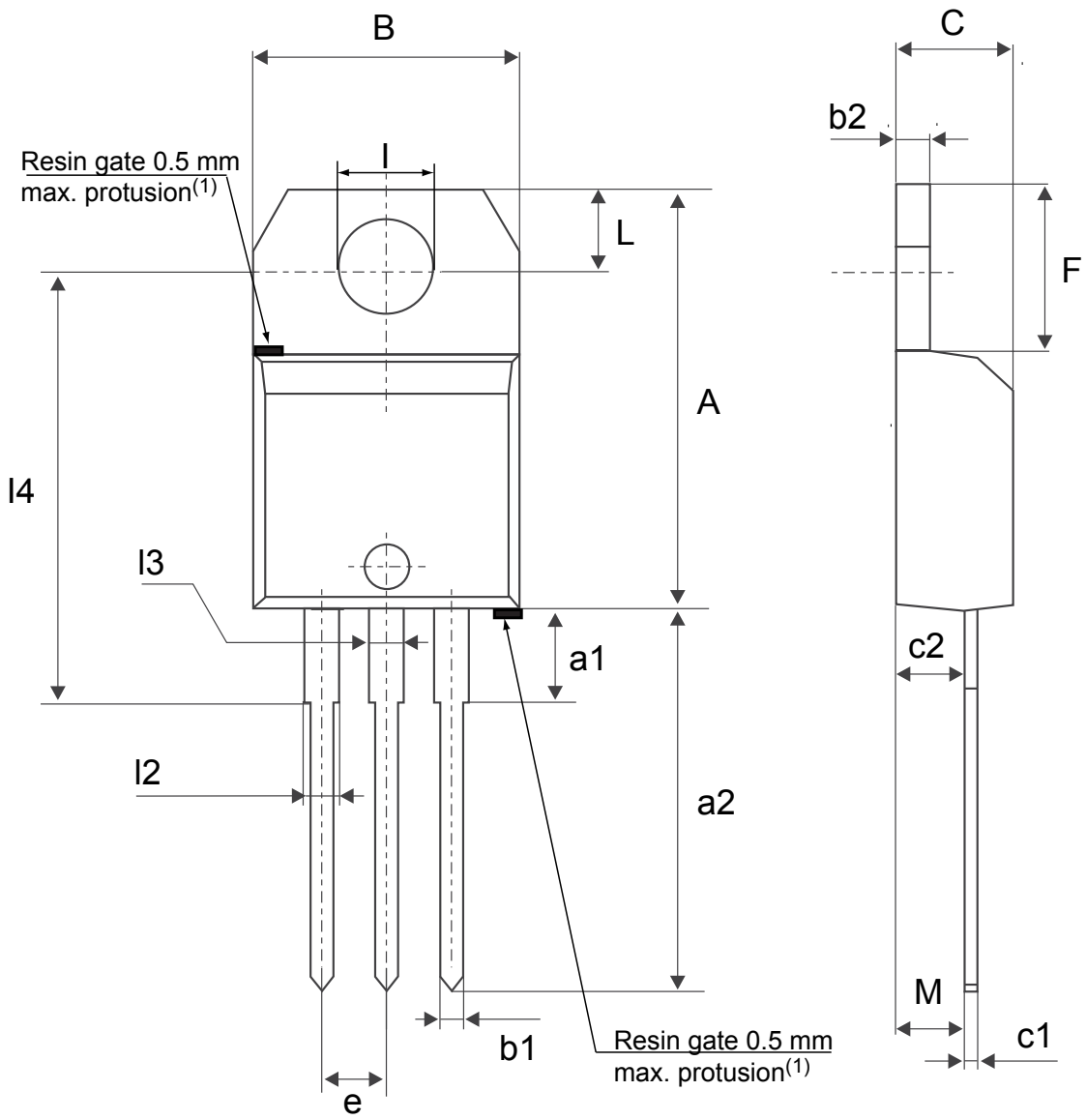
Figure 14. D²PAK recommended footprint (dimensions are in mm)



2.2 TO-220AB insulated package information

- Epoxy meets UL 94,V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 N·m
- Maximum torque value: 0.70 N·m

Figure 15. TO-220AB insulated and non insulated package outline



(1)Resin gate position accepted in one of the two positions or in the symmetrical opposites.

Table 7. TO-220AB insulated and non insulated package mechanical data

Ref.	Dimensions					
	Millimeters			Inches[1]		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.5984		0.6260
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5512
B	10.00		10.40	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0520
C	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0193		0.0276
c2	2.40		2.72	0.0945		0.1071
e	2.40		2.70	0.0945		0.1063
F	6.20		6.60	0.2441		0.2598
I	3.73		3.88	0.1469		0.1528
L	2.65		2.95	0.1043		0.1161
l2	1.14		1.70	0.0449		0.0669
l3	1.14		1.70	0.0449		0.0669
l4	15.80	16.40	16.80	0.6220	0.6457	0.6614
M		2.6			0.1024	

1. *Inch dimensions are for reference only.*

3 Ordering information

Figure 16. Ordering information scheme (BTA12 and BTB12 series)

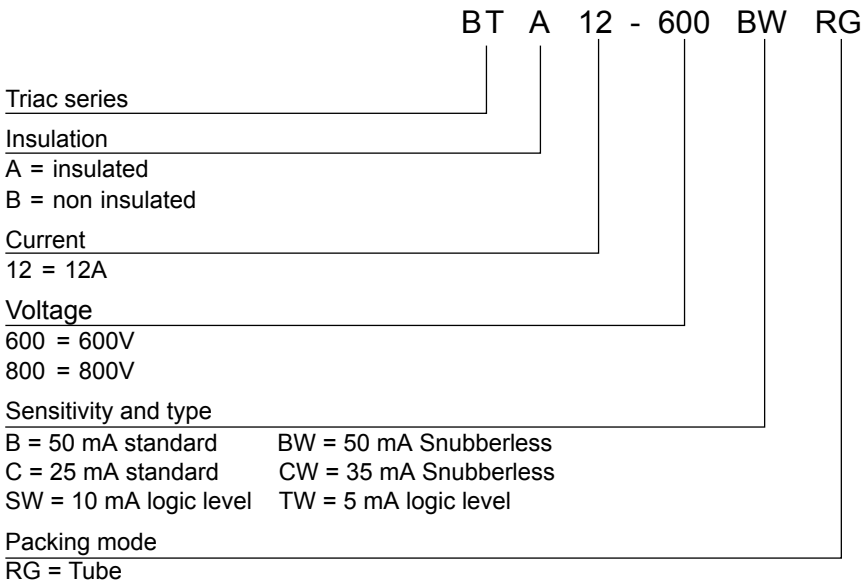


Figure 17. Ordering information scheme (T12 series)

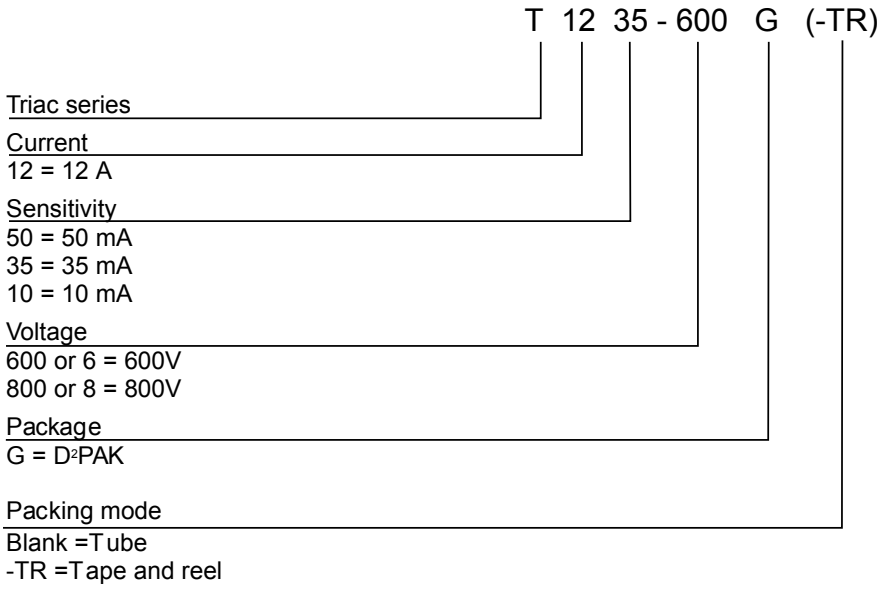


Table 8. **Product selector**

Part number	Voltage (xxx)		Sensitivity	Type	Package
	600	800			
BTB12-600C	X		25 mA	Standard	TO-220AB
BTB12-600B	X		50 mA	Standard	TO-220AB
BTB12-600TW	X		5 mA	Snubberless™	TO-220AB
BTB12-600SW	X		10 mA	Snubberless™	TO-220AB
BTB12-xxxCW	X	X	35 mA	Snubberless™	TO-220AB
BTB12-600BW	X		50 mA	Snubberless™	TO-220AB
BTA12-600C	X		25 mA	Standard	TO-220AB Ins.
BTA12-xxxB	X	X	50 mA	Standard	TO-220AB Ins.
BTA12-600TW	X		5 mA	Snubberless™	TO-220AB Ins.
BTA12-xxxSW	X	X	10 mA	Snubberless™	TO-220AB Ins.
BTA12-xxxCW	X	X	35 mA	Snubberless™	TO-220AB Ins.
BTA12-xxxBW	X	X	50 mA	Snubberless™	TO-220AB Ins.
T1205-600G	X		5 mA	Snubberless™	D²PAK
T1210-6G	X		10 mA	Snubberless™	D²PAK
T1210-800G		X	10 mA	Snubberless™	D²PAK
T1235-xxxG	X	X	35 mA	Snubberless™	D²PAK
T1250-600G	X		50 mA	Snubberless™	D²PAK

Table 9. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
BTA12-600BRG	BTA12-600B	TO-220AB Ins.	1.9 g	50	Tube
BTA12-600BWRG	BTA12-600BW				
BTA12-600CRG	BTA12-600C				
BTA12-600CWRG	BTA12-600CW				
BTA12-600SWRG	BTA12-600SW				
BTA12-600TWRG	BTA12-600TW				
BTA12-800BRG	BTA12-800B				
BTA12-800BWRG	BTA12-800BW				
BTA12-800CWRG	BTA12-800CW				
BTA12-800SWRG	BTA12-800SW				
BTB12-600BRG	BTB12-600B	TO-220AB			
BTB12-600BWRG	BTB12-600BW				
BTB12-600CRG	BTB12-600C				
BTB12-600CWRG	BTB12-600CW				
BTB12-600SWRG	BTB12-600SW				
BTB12-600TWRG	BTB12-600TW				
BTB12-800CWRG	BTB12-800CW				
T1205-600G-TR	T1205-600G	D²PAK	1.38 g	1000	Tape and reel 13"
T1210-6G-TR	T1210-6G				
T1210-800G-TR	T1210-800G				
T1235-600G-TR	T1235-600G				
T1235-800G-TR	T1235-800G				
T1250-600G-TR	T1250-600G				
T1210-6G	T1210-6G			50	Tube
T1235-600G	T1235-600G				

Table 10. Document revision history

Date	Revision	Changes
Sep-2002	6A	Last update.
15-Mar-2005	7	1. I2PAK package added. 2. TO-220AB delivery mode changed from bulk to tube.
27-May-2005	8	T1210 added.
28-Sep-2007	9	Reformatted to current standards. T1250 added.
02-Feb-2017	10	Removed I²PAK package. Updated Figure 7: "Non-repetitive surge peak on-state current" and Table 9: "Product selector" and Table 10: "Ordering information".
9-Aug-2018	11	Updated D²PAK package information and Figure 10. Updated Section Product status / summary.
07-Feb-2019	12	Updated links syntax.

Mouser Electronics

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T1235-600G BTB12-600BWRG BTB12-600TWRG BTB12-600CRG BTA12-800SWRG T1235-600G-TR BTA12-800BWRG BTB12-600BRG BTA12-600BRG BTB12-600SWRG BTB12-600CWRG BTA12-600TWRG BTA12-800CWRG BTA12-800BRG BTA12-600BWRG BTA12-600CWRG BTA12-600SWRG BTB12-800CWRG T1235-800G-TR BTA12-600CRG T1210-800G-TR T1250-600G-TR T1210-6G-TR T1210-6G T1205-600G-TR